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MBR1635 - MBR1660

Features

- Low power loss, high efficiency.
- High surge capacity.
- For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications.
- Metal silicon junction, majority carrier conduction.
- High current capacity, low forward voltage drop.
- Guard ring for over voltage protection.





Schottky Rectifiers

Absolute Maximum Ratings*

T_A = 25°C unless otherwise noted

| Symbol | Parameter | | Value | | | |
|--------------------|---|------|-------------|------|------|---|
| | | 1635 | 1645 | 1650 | 1660 | 1 |
| V_{RRM} | Maximum Repetitive Reverse Voltage | 35 | 45 | 50 | 60 | V |
| I _{F(AV)} | Average Rectified Forward Current .375 " lead length @ T _A = 125°C | 16 | | А | | |
| I _{FSM} | Non-repetitive Peak Forward Surge Current 8.3 ms Single Half-Sine-Wave | 150 | | | | Α |
| T _{stg} | Storage Temperature Range | | -65 to +175 | | | |
| TJ | Operating Junction Temperature | | -65 to +150 | | | |

^{*}These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

Thermal Characteristics

| Symbol | Parameter | Value | Units |
|-----------------|---|-------|-------|
| P _D | Power Dissipation | 2.0 | W |
| $R_{\theta JA}$ | Thermal Resistance, Junction to Ambient | 60 | °C/W |
| $R_{\theta JL}$ | Thermal Resistance, Junction to Lead | 1.5 | °C/W |

Electrical Characteristics T_A = 25°C unless otherwise noted

| Symbol | Parameter | Device | | | | Units |
|------------------|--|-----------|----------|-----------|------|----------|
| | | 1635 | 1645 | 1650 | 1660 | 1 |
| V _F | Forward Voltage $I_{F=}$ 16 A, T_{C} = 25°C $I_{F=}$ 16 A, T_{C} = 125°C | _ | 63 57 | 0.0 | | V |
| I _R | Reverse Current @ rated V_R $T_A = 25^{\circ}C$ $T_A = 125^{\circ}C$ | 0.2 40 | | 1.0 50 | | mA mA |
| I _{RRM} | Peak Repetitive Reverse Surge Current 2.0 us Pulse Width, f = 1.0 KHz | 1.0 | | 0. | 5 | Α |

Schottky Rectifier

(continued)

Typical Characteristics

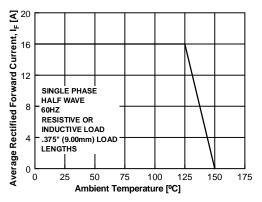


Figure 1. Forward Current Derating Curve

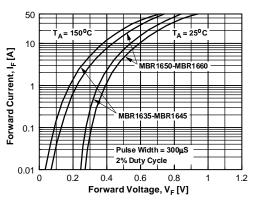


Figure 3. Forward Voltage Characteristics

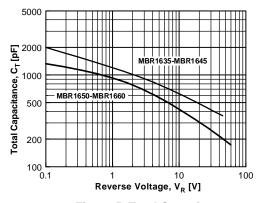


Figure 5. Total Capacitance

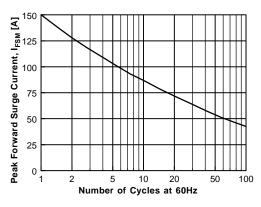


Figure 2. Non-Repetitive Surge Current

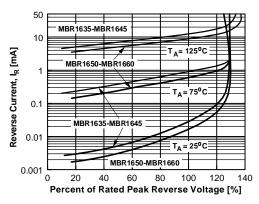


Figure 4. Reverse Current vs Reverse Voltage

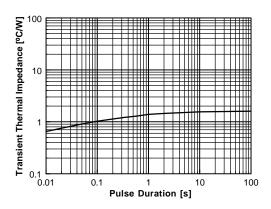


Figure 6. Thermal Impedance Characteristics

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Definition of Terms

| Datasheet Identification | Product Status | Definition |
|--------------------------|---------------------------|---|
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